

Switchmode Full Plastic Single Ultrafast Power Rectifier

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following

Features

- *High Surge Capacity
- *Low Power Loss, High efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage, High Current Capability
- *High-Switching Speed Recovery Time
- * Plastic Material used Carries Underwriters Laboratory
- *Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

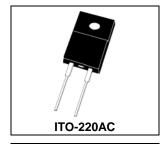
Characteristic	Symbol	UREAF1060	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	600	V
RMS Reverse Voltage	$V_{R(RMS)}$	420	V
Average Rectifier Forward Current Total Device (Rated V_R)	I _{F(AV)}	10	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	10	Α
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-wave, single phase, 60Hz)	I _{FSM}	100	А
Operating and Storage Junction Temperature Range	T_J , T_stg	-65 to +150	$^{\circ}\!\mathbb{C}$

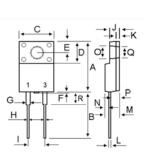
ELECTRICAL CHARACTERISTICS

LELOTRICAL CHARACTERIOTICS					
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25^{\circ}\text{C}$) ($I_F = 10 \text{ Amp } T_C = 125^{\circ}\text{C}$)	V _F		1.35 0.97	1.60	V
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	I _R		0.02 5	10 	uA
Reverse Recovery Time ($I_F = 0.5 \text{ A}, I_R = 1.0, I_{rr} = 0.25 \text{ A}$)	T _{rr}			50	ns
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _P		45		₽F

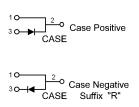
ULTRA FAST RECTIFIER

10 AMPERES 600 VOLTS

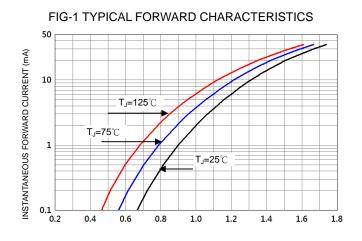




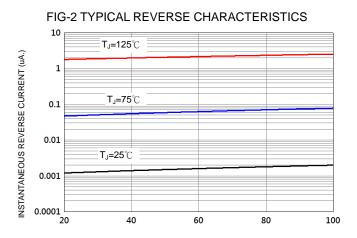
DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	14.80	16.10		
В	12.65	13.80		
С	9.85	10.36		
D	4.60	6.80		
E	2.50	3.50		
F		2.00		
G	1.00	1.45		
Н	0.30	0.90		
- 1	4.80	5.40		
J	2.34	3.30		
K	0.55	1.30		
L	0.36	0.80		
M	4.20	4.90		
N	1.10	1.80		
0	2.90	3.50		
Р	2.50	3.15		
Q	2.90	3.50		
R	3.10	4.85		



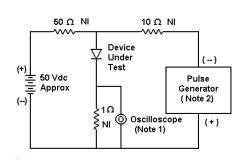




FORWARD VOLTAGE (Volts)

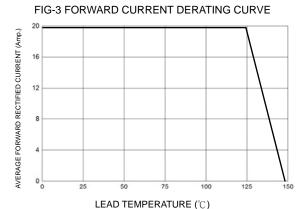


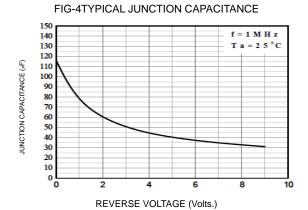


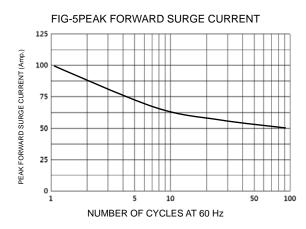


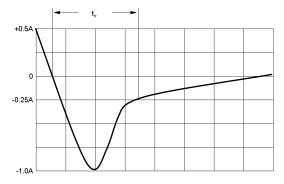
Notes: 1. Rise Time = 7 ns max. Input Impedance = 1 M Ω , 22 pF

2. Rise Time = 10 ns max. Input Impedance = 50Ω









Set time base for 10/20 ns/cm $\,$

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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